L Number	Hits	Search Text	DB	Time stamp
-	293	430/20.ccls.	USPAT	2004/01/28 17:41
-	472	438/30.ccls.	USPAT	2004/01/28 16:43
-	563	438/149.ccls.	USPAT	2004/01/28 17:16
-	127	438/30,149.ccls. and passivation and photoresist	USPAT	2004/01/28 17:23
-	12	438/30,149.ccls. and "first capacitor electrode" and "second capacitor electrode"	USPAT	2004/01/28 17:24
-	44	438/30,149.ccls. and samsung.as.	USPAT	2004/01/28 17:26
-	5	438/30,149.ccls. and pattern$ with "active layer" with "passivation layer"	USPAT	2004/01/28 17:30
-	59	438/30,149.ccls. and lg.as.	USPAT	2004/01/28 17:30
-	34	438/30,149.ccls. and "masking step"	USPAT	2004/01/28 17:31
-	12	438/30,149.ccls. and "first metal layer" and "second metal layer" and "active layer"	USPAT	2004/01/28 17:31
-	50	438/30,149.ccls. and "first metal layer" and "second metal layer"	USPAT	2004/01/28 17:35
-	951	257/59.ccls.	USPAT	2004/01/28 17:35
-	855	257/72.ccls.	USPAT	2004/01/28 17:35
-	8	257/59,72.ccls. and pattern$ with passivation with "active layer"	USPAT	2004/01/28 17:36
-	65	257/59,72.ccls. and "first metal layer" and "second metal layer"	USPAT	2004/01/28 17:37
-	15	257/59,72.ccls. and "first capacitor electrode" and "second capacitor electrode"	USPAT	2004/01/28 17:37
-	177	257/59,72.ccls. and passivation and photoresist	USPAT	2004/01/28 17:37
-	60	257/59,72.ccls. and samsung.as.	USPAT	2004/01/28 17:37
-	79	257/59,72.ccls. and lg.as.	USPAT	2004/01/28 17:38
-	27	257/59,72.ccls. and "masking step"	USPAT	2004/01/28 17:39
-	48	430/$.ccls. and "halftone mask"	USPAT	2004/01/28 17:40
-	108	349/38,39,42,43,44.ccls. and passivation and photoresist	USPAT	2004/01/28 17:40
-	22	349/38,39,42,43,44.ccls. and "first capacitor electrode" and "second capacitor electrode"	USPAT	2004/01/28 17:40
-	96	349/38,39,42,43,44.ccls. and passivation and "active layer"	USPAT	2004/01/28 17:42
-	444	349/187.ccls.	USPAT	2004/01/28 17:42
-	68	349/38,39,42,43,44.ccls. and samsung.as.	USPAT	2004/01/28 17:42
-	108	349/38,39,42,43,44.ccls. and lg.as.	USPAT	2004/01/28 17:42